





ZXMP4A57E6

#### **40V P-CHANNEL ENHANCEMENT MODE MOSFET**

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C
-40V	$80 \text{m}\Omega$ @ $V_{GS}$ = -10 $V$	-3.7 A
-40 V	150mΩ @ V <sub>GS</sub> = -4.5V	-2.8 A

### **Description**

This MOSFET has been designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

### **Applications**

- Motor Control
- DC-DC Converters
- Power Management Functions
- Uninterrupted Power Supply

#### **Features and Benefits**

- Fast switching speed
- Low gate drive
- Low input capacitance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

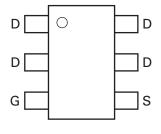
#### **Mechanical Data**

- Case: SOT26
- Case Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper lead frame.
   Solderable per MIL-STD-202, Method 208 (3)
- Weight 0.018 grams (approximate)

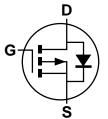
SOT26



Top View



Top View Pin-Out



**Equivalent Circuit** 

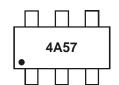
### Ordering Information (Note 4 & 5)

Part Number	Compliance	Case	Quantity per reel
ZXMP4A57E6TA	Standard	SOT26	3,000
ZXMP4A57E6QTA	Automotive	SOT26	3,000

Notes:

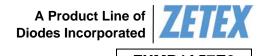
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_grade\_definitions/.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



4A57 = Product Type Marking Code





ZXMP4A57E6

# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage		$V_{DSS}$	-40	V	
Gate-Source Voltage		$V_{GS}$	±20	V	
		(Note 7)		-3.7	
Continuous Drain Current	$V_{GS} = 10V$	$T_A = +70^{\circ}C \text{ (Note 7)}$	$I_{D}$	-2.9	Α
		(Note 6)		-2.9	
Pulsed Drain current	$V_{GS} = 10V$	(Note 8)	I <sub>DM</sub>	-18	Α
Continuous Source Current (Body Diode) (Note 7)		(Note 7)	Is	-2.6	А
Pulsed Source Current (Body Diode) (Note 8)		I <sub>SM</sub>	-18	Α	

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power dissipation	(Note 6)		1.1 8.8	W	
Linear derating factor	(Note 7)	P <sub>D</sub>	1.7 13.7	mW/°C	
Thermal Desistance Junction to Ambient	(Note 6)	D.	113	°C/W	
Thermal Resistance, Junction to Ambient	(Note 7)	R <sub>θJA</sub>	73	- *C/VV	
Operating and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

Notes:

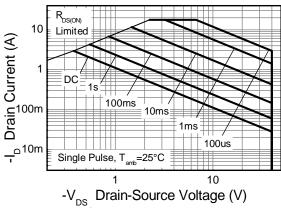
<sup>6.</sup> For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

<sup>7.</sup> Same as note (4), except the device is measured at  $t \le 5$  sec.

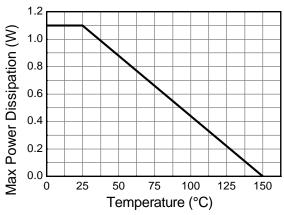
<sup>8.</sup> Same as note (4), except the device is pulsed with D = 0.02 and pulse width 300µs. The pulse current is limited by the maximum junction temperature.



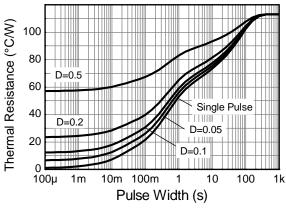
# **Thermal Characteristics**



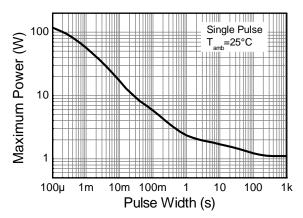
P-channel Safe Operating Area



**Derating Curve** 



**Transient Thermal Impedance** 



**Pulse Power Dissipation** 





**ZXMP4A57E6** 

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Co	ondition
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-40	_	_	V	$I_D = -250 \mu A, V_{GS} = 0 V$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	-0.5	μΑ	$V_{DS} = -40V, V_{GS}$	= 0V
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS}$	= 0V
ON CHARACTERISTICS							
Gate Threshold Voltage	$V_{GS(th)}$	-1.0	_	-3.0	V	$I_D = -250 \mu A, V_{DS}$	= V <sub>GS</sub>
Static Drain-Source On-Resistance (Note 9)	J	_	_	0.080	Ω	$V_{GS} = -10V, I_D =$	-4A
Static Dialif-Source Off-Resistance (Note 9)	R <sub>DS(ON)</sub>	_	_	0.150	12	$V_{GS} = -4.5V, I_D =$	-2A
Forward Transconductance (Notes 9 & 10)	g <sub>fs</sub>	_	7.6	_	S	$V_{DS} = -15V, I_{D} =$	-4A
Diode Forward Voltage (Note 9)	V <sub>SD</sub>	_	-0.86	-0.95	V	I <sub>S</sub> = -4A, V <sub>GS</sub> = 0V	
Reverse recovery time (Note 10)	t <sub>rr</sub>	_	17.4	_	ns	-I <sub>S</sub> = -1.8A, di/dt = 100A/μs	
Reverse recovery charge (Note 10)	Q <sub>rr</sub>	_	11.1	_	nC		
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C <sub>iss</sub>	_	833	_			
Output Capacitance	Coss	_	122	_	pF $V_{DS} = -20V$ , $V_{GS} = 0V$ f = 1MHz		= 0V
Reverse Transfer Capacitance	C <sub>rss</sub>	_	78	_		I = IIVII IZ	
Total Gate Charge (Note 11)	Qg	_	7	_		$V_{GS} = -4.5V$	
Total Gate Charge (Note 11)	Qg	_	15.8	_	V <sub>DS</sub> = -20V		$V_{DS} = -20V$
Gate-Source Charge (Note 11)	$Q_{gs}$	_	3.6	_	nC	$V_{GS} = -10V$ $I_D = -4A$	$I_D = -4A$
Gate-Drain Charge (Note 11)	Q <sub>gd</sub>	_	2.7	_			
Turn-On Delay Time (Note 11)	t <sub>D(on)</sub>	_	2.5	_		V <sub>DD</sub> = -20V, V <sub>GS</sub> = -10V	
Turn-On Rise Time (Note 11)	tr	_	3.3	_			
Turn-Off Delay Time (Note 11)	t <sub>D(off)</sub>	_	47		ns $I_D = -1A$ , $R_G \cong 6.0\Omega$		<b>Ο</b> Ω
Turn-Off Fall Time (Note 11)	t <sub>f</sub>		21				

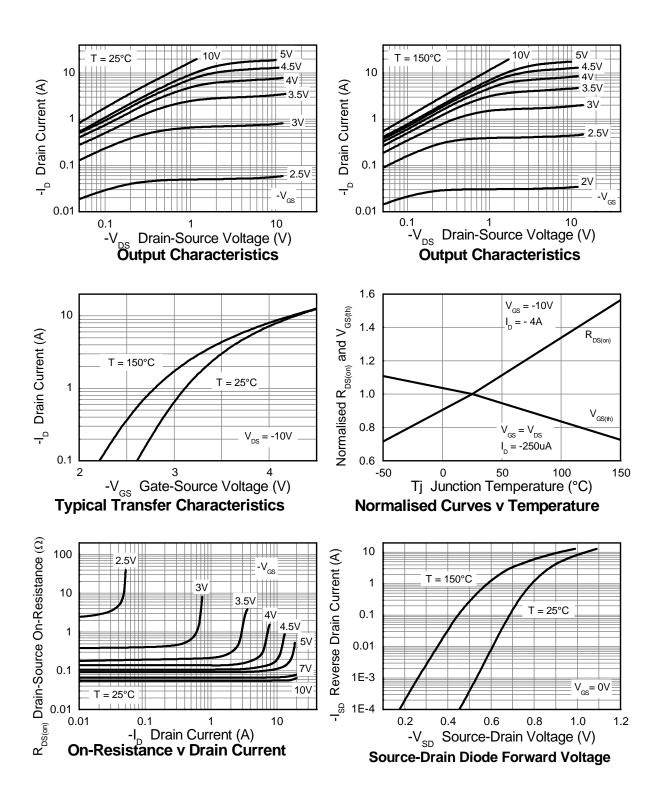
Notes:

<sup>9.</sup> Measured under pulsed conditions. Pulse width  $\leq$  300µs; duty cycle  $\leq$  2%.

<sup>10.</sup> For design aid only, not subject to production testing.
11. Switching characteristics are independent of operating junction temperatures.

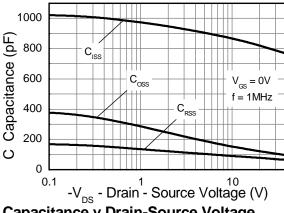


# **Typical Characteristics**





# **Typical Characteristics** (cont.)



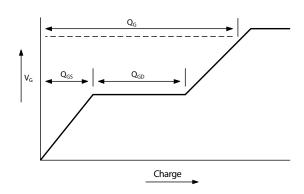
Gate-Source Voltage (V) 6 2 4 6 8 10 Q - Charge (nC) 12

10

Capacitance v Drain-Source Voltage

**Gate-Source Voltage v Gate Charge** 

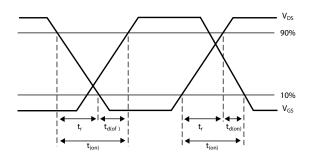
### **Test Circuits**

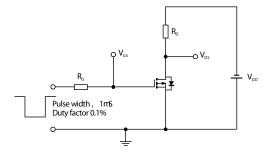


Current regulator 12V J**⊑** ⊉ D.U.T

Basic gate charge waveform

Gate charge test circuit





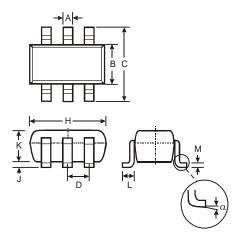
Switching time waveforms

Switching time test circuit



# **Package Outline Dimensions**

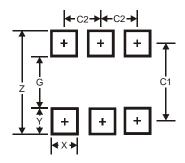
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT26					
Dim	Min	Max	Тур			
Α	0.35	0.50	0.38			
В	1.50	1.70	1.60			
С	2.70	3.00	2.80			
D	_	_	0.95			
Н	2.90	3.10	3.00			
J	0.013	0.10	0.05			
K	1.00	1.30	1.10			
L	0.35	0.55	0.40			
М	0.10	0.20	0.15			
α	0°	8°	_			
All Dimensions in mm						

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.



Dimensions	Value (in mm)		
Z	3.20		
G	1.60		
Х	0.55		
Y	0.80		
C1	2.40		
C2	0.95		





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